

21.6 Microelectromechanical Scanning Devices for Optical Networking Applications

Ming C. Wu, Dooyoung Hah, Pamela R. Patterson, Hiroshi Toshiyoshi¹

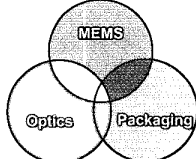
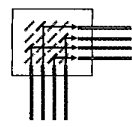
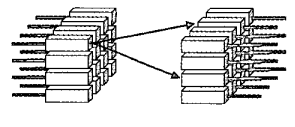
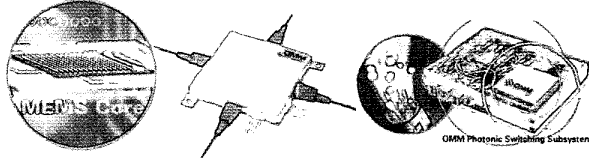
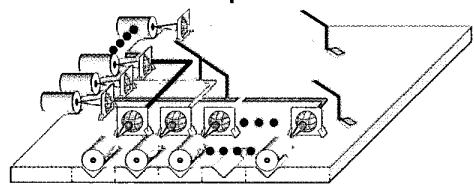
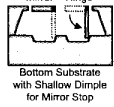
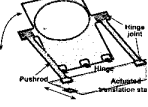
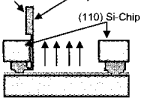
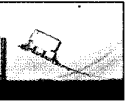
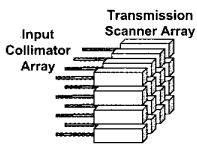
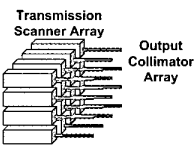
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M. Wu

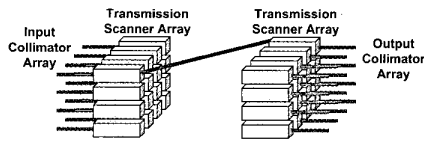
The state-of-the-art of optical MEMS devices for optical networking applications is reviewed, and a scanning micromirror with angular vertical comb (AVC) actuators is introduced. The AVC scanner uses a single etching process and is completely self-aligned. It has 50% larger scan angle than conventional vertical comb devices. Resonant frequency is 630Hz.

See Digest page 358

<h3 style="text-align: center;">OUTLINE</h3> <ul style="list-style-type: none"> • Introduction • 2D MEMS optical switches – Lessons learned • 3D MEMS optical switches <ul style="list-style-type: none"> – Critical issues for MEMS scanners – New scanner using angular vertical comb drive actuators • Conclusion 	<h3 style="text-align: center;">Critical Issues of 2D MEMS Switches</h3>  <ul style="list-style-type: none"> • Concurrent engineering of MEMS, Optics and Packaging <ul style="list-style-type: none"> – MEMS: <ul style="list-style-type: none"> • Mirror angle accuracy, uniformity, repeatability; Fill factor; Stiction – Optics: <ul style="list-style-type: none"> • Fiber collimator array; Optical alignment (active) – Packaging <ul style="list-style-type: none"> • Fix and maintain alignment (for 20 years); Hermetic sealing; Resistance to temperature variation; Reliability
<h3 style="text-align: center;">MEMS Optical Switch Architectures</h3> <div style="display: flex; justify-content: space-around;"> <div data-bbox="243 1060 487 1249"> <h4 style="text-align: center;">2-D MEMS Digital Crossbar Switch</h4>  </div> <div data-bbox="511 1060 803 1249"> <h4 style="text-align: center;">3-D MEMS Analog Beam-Steering Switch</h4>  </div> </div> <ul style="list-style-type: none"> • N^2 digital micromirrors • Digital switch, easy to control • Maximum size of the switch limited by diffraction (32x32) <ul style="list-style-type: none"> – Multi-stage network (e.g., Clos) needed to large OXC <ul style="list-style-type: none"> • 2N analog scanners (2 DOF) • Close-loop control for each scanner • Scalable to large port count (> 1000) 	<h3 style="text-align: center;">Current Status of 2D MEMS Optical Switch</h3>  <ul style="list-style-type: none"> • 2-D MEMS optical switch has been successfully commercialized • 4x4, 8x8, 16x16, and 32x32 are now commercially available in quantities • Telcordia qualifications (GR-1073-CORE, GR-1221-CORE and GR-468-CORE) passed • Automation in assembly, packaging, and testing is key to volume production
<h3 style="text-align: center;">2D MEMS Optical Switches</h3>  <div style="display: flex; justify-content: space-around; margin-top: 10px;"> <div data-bbox="219 1659 332 1795">  <p>Bulk Micromachined Mirror + Hinge Bottom Substrate with Shallow Dimple for Mirror Stop</p> <p>Toshiyoshi, Fujita '98 (Tokyo University)</p> </div> <div data-bbox="349 1659 495 1795">  <p>Switch mirror Postrod Actuator verification via</p> <p>L. Y. Lin '98 (AT&T Lab)</p> </div> <div data-bbox="511 1659 657 1795">  <p>Electroplated Nickel Poly-Si Plate (110) Si Chip</p> <p>Behin, Lau, Muller, '98 (UC Berkeley)</p> </div> <div data-bbox="673 1659 803 1795">  <p>Curled Cantilever Switch to reduce voltage (<20 V)</p> <p>Chan, Nguyen, Wu, '99 UCLA</p> </div> </div>	<h3 style="text-align: center;">3-D Switch using Analog Scanners</h3> <div style="display: flex; justify-content: space-around; margin-bottom: 10px;"> <div data-bbox="860 1512 1023 1606"> <p>1. Transmission type with Scanning Microlenses</p> </div> <div data-bbox="1047 1480 1242 1627">  </div> <div data-bbox="1291 1480 1485 1627">  </div> </div> <div data-bbox="860 1711 1023 1806"> <p>2. Reflection type with Scanning Micromirrors</p> </div>

3-D Switch using Analog Scanners

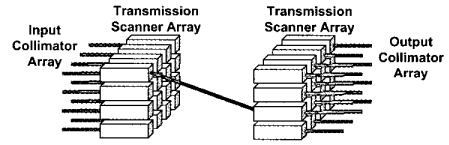
1. Transmission type with Scanning Microlenses



2. Reflection type with Scanning Micromirrors

3-D Switch using Analog Scanners

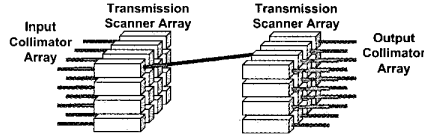
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3-D Switch using Analog Scanners

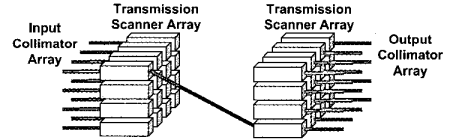
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3-D Switch using Analog Scanners

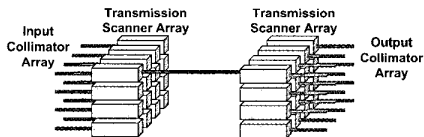
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3-D Switch using Analog Scanners

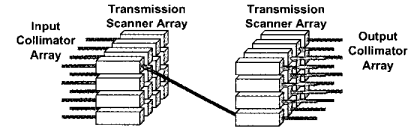
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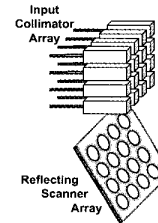
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3-D Switch using Analog Scanners

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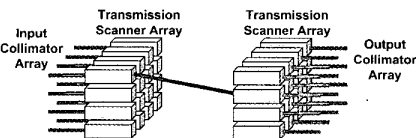


2. Reflection type with Scanning Micromirrors



3-D Switch using Analog Scanners

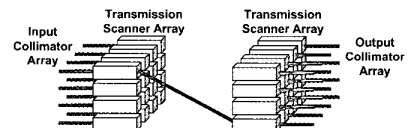
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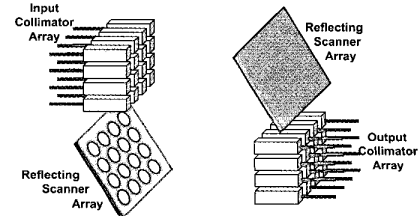
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3-D Switch using Analog Scanners

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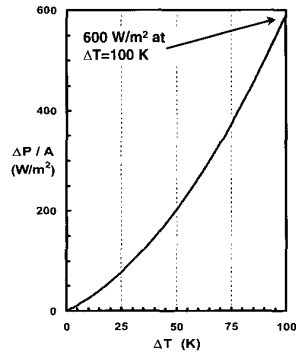


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Measurement of Chip Cooling with E-jet

- Heat transfer capacity increases to 600 W/m² at $\Delta T = 100$ K
- Stable operation: >6B cycles
- Typical human cooling requirement is 360-700 W/m²
- Mobile Pentium III (0.5-1 GHz) cooling requirement: 10-50 kW/m²



Power Consumption and Efficiency

- Consumed power in the 25 resonator MACE by device and parasitic capacitances is ~300mW.
- A high voltage source of ~100V is needed since MACE. This is not a major issue since charge-pump circuits can be used to accommodate this higher voltage.
- Efficiency can be improved by recovering some of the energy currently wasted in charging and discharging the capacitors.
- Significant energy is used up in moving the air around and this depends on the flow rate and air volume needed for a particular application. This is the dominant power dissipation source and cannot be reduced.
- E-jet is expected to be at least as efficient as some of the standard fans used in portable systems.

Future Development

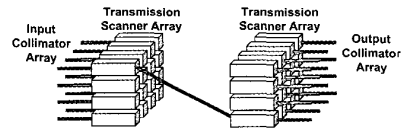
- Clearly the heat removal rate of the current devices is not sufficient for high-power electronic devices.
- The e-jet velocity needs to be increased.
- New designs are in development that can increase the jet velocity by a factor of about 10x
- The total volume of pumped air can be increased by using a larger number of devices.
- Further work is necessary to optimize the assembly and attachment of e-jets to the IC chip.
- Further long-term stability and reliability tests are needed.
- Active Pin-Fin heat sink should provide a higher efficiency.

Conclusions and Summary

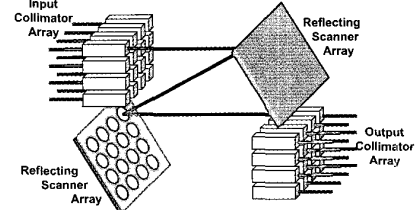
- A stand-alone micromachined electronic jet capable of producing air flow velocity of 0.5-1 m/sec has been developed.
- E-jet is fully integrated and does not require external components for its operation.
- E-jet is quiet (50-70kHz), and is electrostatically operated.
- E-jet is thin (<2mm), and small (few cm on a side) and can be mounted directly over the IC chip package, without interfering with the manufacturing of the IC chip.
- E-jet can be used for air pumping and cooling applications in a variety of portable electronic devices.

3-D Switch using Analog Scanners

1. Transmission type with Scanning Microlenses

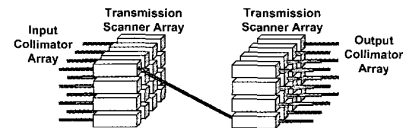


2. Reflection type with Scanning Micromirrors

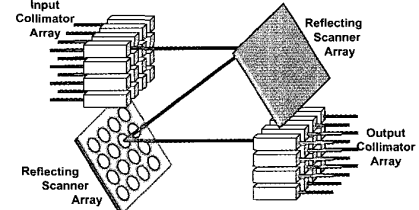


3-D Switch using Analog Scanners

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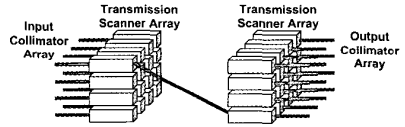


2. Reflection type with Scanning Micromirrors

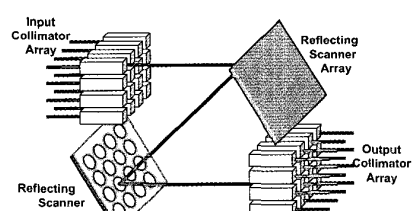


3-D Switch using Analog Scanners

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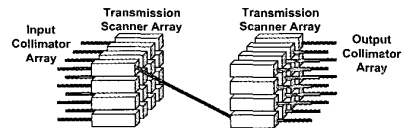


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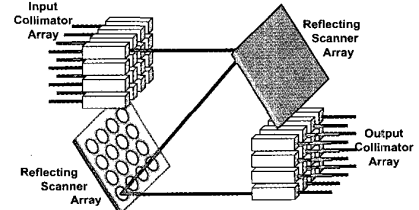


3-D Switch using Analog Scanners

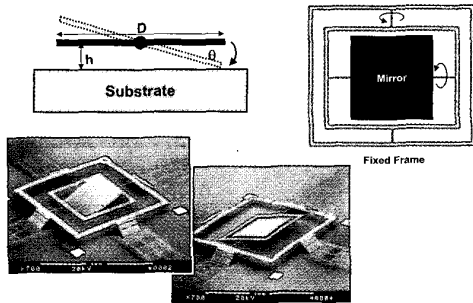
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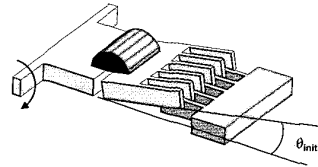


Surface-Micromachined 2-D Scanning Micromirrors



L. Fan, M. C. Wu, Optical MEMS 1998

New Angular Vertical Comb Drive Actuator

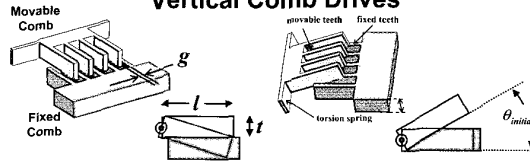


- Movable comb is tilted by an initial angle
- Offers many advantages over staggered vertical combs:
 - Simpler fabrication process; need only a single-layer SOI
 - Self-aligned, both movable and fixed combs are patterned and etched at the same time
 - Increased threshold for lateral instability
 - Larger scan angle (determined by the initial tilt angle)

Critical Issues for 2D Scanners

- Flat mirror surface over wide temperature range
- Large mirror area, large scan angle
- Low actuation voltage (or energy)
- Reasonably high resonant frequency
- High fill factor
- Low crosstalk among scanners
- Good repeatability
- Low drift

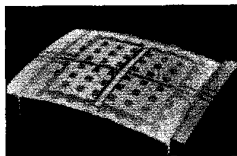
Comparison of Staggered and Angular Vertical Comb Drives



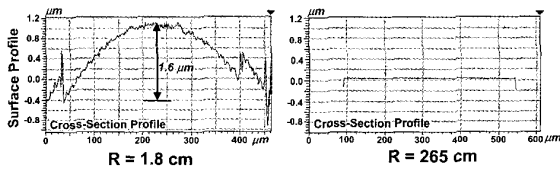
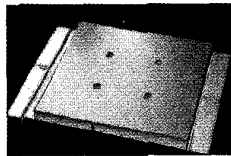
	Staggered Vertical Comb (SVC)	Angular Vertical Comb (AVC)
Torque per Gap	$\tau = \frac{\epsilon \cdot l^2}{2g}$	$\tau = \frac{\epsilon \cdot l^2}{2g}$
Maximum Scan Angle	$\theta_{max} = \frac{l}{t}$	$\theta_{max} = \theta_{initial} > \frac{l}{t}$

Micromirror Flatness

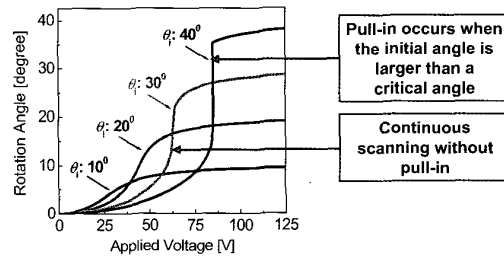
Polysilicon Mirror



Single Crystalline Si Mirror



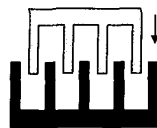
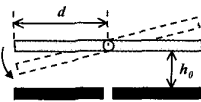
Calculated Scanning Characteristics of AVC Scanner



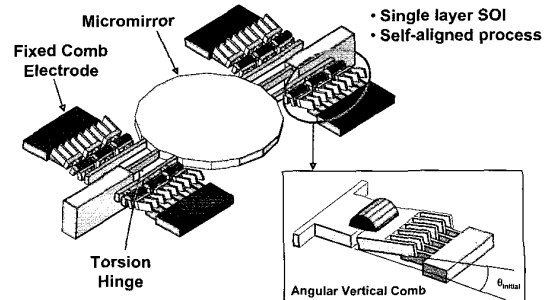
The maximum angle without pull-in is 50% larger than SVC scanner with same comb dimensions

Considerations for Actuators (Electrostatic)

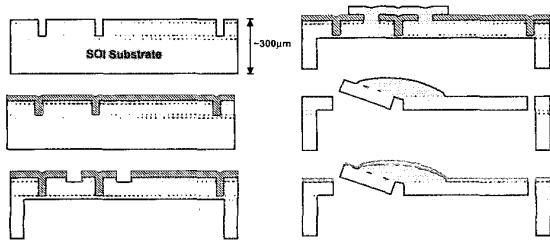
- Parallel plate actuators
 - Large, flat single-crystalline micromirrors with large scan angle has been demonstrated [Blackstone, 2001; Sawada, 2001]
 - Issues: High voltage; Usable angle reduced by pull-in bistability
- Vertical comb actuators
 - Large force density
 - Low voltage, large scan range, high resonant frequency
 - Initially demonstrated by surface/bulk-micromachining [Selvakumar, 1995]
 - Staggered vertical comb using double-



Schematic of Micromirror with Angular Vertical Comb (AVC) Actuator

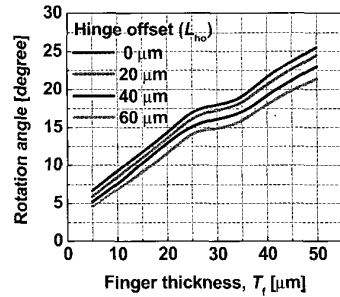


Fabrication Process for AVC Scanner



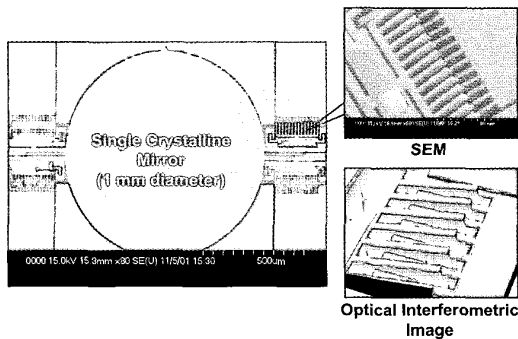
- One-step DRIE on SOI wafer
- Self-aligned fixed and movable comb fingers
- Use reflow of photoresist for 3D assembly (after Syms)

Maximum Scan Angle versus Thickness of SOI

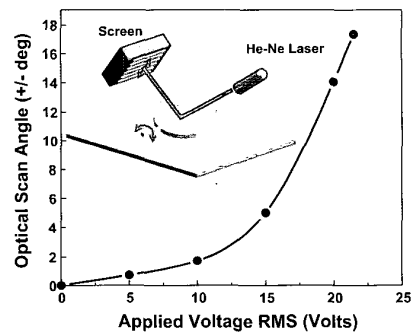


- Bias voltage kept constant at 100 V
- Finger length and initial tilt angle are optimized for maximum angle

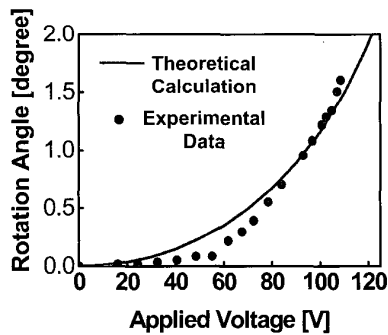
Scanning Electron Micrograph of AVC Scanner



Resonant Scanning Angle at 1.4 kHz



Measured Scanning Characteristics



Conclusion

- MEMS is a disruptive technology for optical systems
- Attractive for dynamic all-optical functions
- Successful commercialization Optical MEMS products requires concurrent engineering of
 - MEMS, Optics, Packaging
- Reviewed status of 2D and 3D MEMS optical switches
- Discussed angular vertical comb (AVC) actuator for scanning mirrors that is promising for large area, large scan angle micromirrors

Optimization of AVC Scanner

